

L Number	Hits	Search Text	DB	Time stamp
1	1	second adj strain adj relief adj plate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:13
2	30501	second adj plate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:13
3	12800	strain adj relief	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:13
4	100	(second adj plate) and (strain adj relief)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:19
5	319	257/107.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:29
6	0	((second adj plate) and (strain adj relief)) and 257/107.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:20
7	0	(strain adj relief) and 257/107.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:21
8	0	(second adj plate) and 257/107.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:21
9	282137	257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:21
10	4	((second adj plate) and (strain adj relief)) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:22
11	36282	pressure adj contact	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:29
12	1	257/107.ccls. and (pressure adj contact)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:30

13	3192	GTO and Thyristor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:31
15	1	((GTO and Thyristor) and (pressure adj contact)) and (second adj plate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 14:31
14	73	(GTO and Thyristor) and (pressure adj contact)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 16:01
16	67018	dummy	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 16:02
17	0	((GTO and Thyristor) and (pressure adj contact)) and dummy	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 16:32
18	215610	semiconductor adj substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 16:33
19	1736386	substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 16:34
20	1384597	semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 16:34
21	575234	substrate and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 16:58
22	96	GCT and thyristor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 16:59
23	0	(GCT and thyristor) and dummy	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/07 16:59